157nm University Resist Research Project

(09-12-01)

Will Conley-Motorola Assignee Danny Miller-International SEMATECH Paul Zimmerman-Intel Assignee



Welcome to Paul Zimmerman; Intel Assignee









157nm University Resist Research Project Team

SEMATECH

•Will Conley

•Jeff Byers

•Dan Miller

•Georgia Rich

•Vicki Graffenberg

•Shashi Patel

<u>UT</u>

Matt Pinnow

• Raymond Hung

•Brian Osborne

Shintaro Yamada

•Tony Van Hayden

•Hoang Vi Tran

•Brian Trinque

•Jordan Owens

•Vincent ????

Cal-Tech

Prof Grant Willson
Prof Grubbs

•Dan Sanders

•John Klopp

•Nick Benzal

UC-Berkeley

•Prof Jean Frechet

<u>Clemson</u>

•Prof Darryl DesMarteau

•Brian Thomas

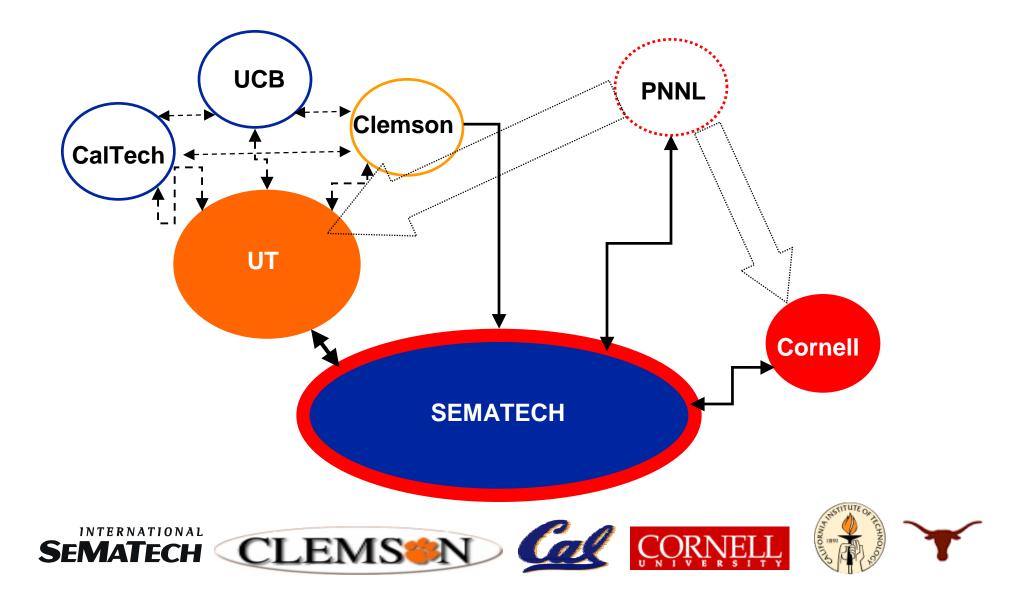
•Greg Shafer

Cornell University

•Prof Chris Ober



157nm University Resist Research Project Team



SEMATECH Sept 2001 RAG-Presentation Agenda

SEMATECH

Will Conley

Clemson

Brian Thomas- C_2F_4

Cornell

V. Vora - Acrylate Platforms

Berkeley

Nick Benzal- Mass Persistence

The University of Texas

Brian Osborn – ROMP and Metal catalyzed addition polymers Charles Chambers – Free radical polymerization Brian Trinque – Acrylate copolymer based resists Takashi Ciba – CO co-polymers and dissolution inhibitors Will Conley – Process studies Summary and Questions



Ref.	Parameter	Development Specs	Manufacturing Specs10 mJ/cm2 @ 157 nm				
3.2.1	Photospeed	15 mJ/cm ² @ 157 nm					
3.2.2	Ultimate Resolution 1:1 Pitch 1:1.5 Pitch Isolated Lines	0.60 NA tool @ 157 nm 120 nm 100nm 90nm	0.60 NA tool @157 nm 100 nm 90nm 70nm				
3.2.3	Image Stability	30 minutes	1 hour				
3.2.4	Exposure Latitude	±8%	±10%				
3.2.5	Focus Latitude	±0.175 µm	±0.175 µm				
3.2.6	Isolated-to-Group Bias	10%	5%				
3.2.7	Linear Resolution 1:1 Pitch 1:1.5 Pitch Isolated Lines	0.60 NA tool @ 157 nm 120 nm 110nm 100nm	0.60 NA tool @157 nm 110 nm 100nm 80nm				
3.2.8	Sidewall Slope	86 -92	87 -90° (no foot or cap)				
3.2.9	Thermal Stability	2 min @ 130C	same as Development				
3.2.10	Post-Exposure Bake (PEB) Time	< 90 sec	same as Development				
3.1.11	Etch Resistance	Feasibility for 1000A poly etch	20% resist remaining after 1000A poly etch				
3.1.12	Line Edge Roughness	2% (1 σ)	1% (1 σ)				
3.1.13	Contact Holes	130nm 1:1 Pitch	120nm 1:1 Pitch				

3.1 Performance Targets for 157 nm Resist Systems

****** Transmission accounted for in resist thickness requirements









LITJ102: University 157nm Resist and Process Research

Objectives:

- Gain fundamental understanding of physics and chemistry of 157nm resists
- Develop model resist platforms for 157nm resist.
- Demonstrate performance for 70 and 100nm technology generations

Benefits:

- Open resist platforms available to worldwide suppliers
- Early learning from a model resist platform
- Leadership position relative to new developments

Approach:

- Build on the successes of the 193nm project
- Team with other university researchers
- Team with resist suppliers and researchers from around the world

Deliverables

- Resist samples every four months to progressively tighter performance criteria
- Yearly Materials Progress Checkpoints
- Material Transparency Report 2Q00
- Zero-diffusion resist by 2Q01
- Zero-outgassing resist by 4Q01
- Final project report 4Q02







SEMATECH-UT 157nm Materials Research Program Schedule-Overview

	4Q '99	1Q'00	2Q'00	3Q'00	4Q'00	1Q'01	2Q'01	3Q'01	4Q'01	1Q '02	2Q '02	3Q '02	4Q '02	
Contract Negotiations	ţ													
Program Scheduling	\bullet													
Material Transparency														
Studies & Report														
1st Material Evaluation:														
Formulated Sample Due	ľ			· ·										
2nd Material Evaluation														
for 130nm resolution 1:1														
in 100nm of Resist														
Formulated Sample Due														
Checkpoint on Mtls Path					•									
(option narrowing)					•									
Report on Zero Outgassing														
3rd Material Evaluation														
Formulated Sample Due														
No Gas Resist Report														
4th Material Evaluation														
Formulated Sample Due												_		
· · · · · · · · · · · · · · · · · · ·										MPL	EEI	nd of	f Thi s	s Mon
5th Material Evaluation:														
(1:1) & 100nm														
Res@150nm thick (1:1)														
Formulated Sample Due														
Checkpoint on Mtls Path														
(option narrowing) /														
Program Assessment													A OF	









SEMATECH-UT 157nm Materials Research Program Schedule-Overview

	4Q '99	1Q'00	2Q'00	3Q'00	4Q'00	1Q'01	2Q'01	3Q'01	4Q'01	1Q '02	2Q '02	3Q '02	4Q '02	10 '03
6th Material Evaluation,														
Zero Outgassing/low														
diffusion Resist														
Formulated Sample Due														
7th Material Evaluation:														
Formulated Sample Due														
8th Material Evaluation:														
or 100nm resolution @														
300nm thick (1:1) / IST-														
70nm resolution in 150nm														
resist														
Formulated Sample Due														
Final Project Review													•	
Final Project Review & Rep	ort													



This Reporting Period

- •New DI's
- •Free Radical Polymerizations
- •More transparency
- •Transparency requirements
- •Imaging & processing data

Due this month

5th Sample

• 100nm 1:1 in 150nm of Photoresist



Cornell Contract Extension

•Statement of Work extended

•First year summary meeting in early October with report to follow

- •Contract extension signed by Cornell and ISMT
- •2 additional researchers added to staff
- •No research interruption



Clemson Contract Extension

- •Statement of Work extended & at Clemson
- •First year summary meeting in early October with report to follow
- •1 additional grad student added to project
- •No research interruption



Pacific Northwest National Labs (PNNL)

•People

•Dave Dixon, Associate Director for Theory, Modeling & Simulation

•5 yrs at PNNL

•Computational aspects of fluorine chemistry

•12 years Dupont

•Calculation thermochemical & kinetic properties of alternatives for CFC's.

•Chang-Guo Zhan, visiting scientist from Columbia University, Ph.Ds in chemistry and physics

•Mission: Establish a program of research in computational molecular science, combining the elements of theoretical and computational chemistry, and materials science with computer science, applied mathematics, and advanced computing technologies, to provide a molecular level understanding of complex processes in various environments.

□ Recent work with with EUV, recent work with SELETE on F_2 □ Focus of this work is to further develop model capability to support Universities and Resist Companies in the accurate prediction of spectra.



Pacific Northwest National Labs (PNNL)

•Progress and Plans

- •Contract signed in late August
- •Kick-off meeting held and milestones discussed
- •Progress report to the next RAG will be made by David Dixon/Chang-Guo Zhan

•Scheduled FTF in late October or early November

